

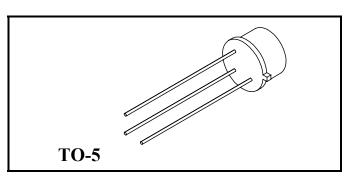
Phone: (562) 404-4474 \* Fax: (562) 404-1773 ssdi@ssdi-power.com \* www.ssdi-power.com SSR0508/5 SSR0509/5 SSR0510/5

## Designer's Data Sheet

## **FEATURES:**

- **Extremely Low Forward Voltage Drop**
- Low Reverse Leakage
- **Hermetically Sealed Package**
- **Guard Ring for Overvoltage Protection**
- **Eutectic Die Attach**
- 175°C Operating Junction Temperature
- TX, TXV, or Space Level Screening Available

## **5 AMP** 80 - 100 VOLTS**SCHOTTKY RECTIFIER**



MAXIMUM RATINGS			
RATING	SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage and DC Blocking Voltage SSR0508/5 SSR0509/5 SSR0510/5	$ m V_{RRM}$ $ m V_{RWM}$	80 90 100	Volts
	$V_R$		
Average Rectified Output Current			
(Resistive Load, 60Hz, Sine Wave, TA=25°C)	$I_0$	5	Amps
Peak Surge Current <sup>1/2</sup> (8.3 ms Pulse, Half Sine Wave, superimposed on I <sub>O</sub> , allow junction to reach equilibrium between pulses, TA=25°C)	$\mathbf{I}_{\mathrm{FSM}}$	150	Amps
Operating and Storage Temperature	T <sub>OP</sub> & T <sub>STG</sub>	-65 to +175	°C
Maximum Thermal Resistance 1/			
Junction to Case	$R_{ m 0JC}$	7	°C/W

1/ For optimal performance, connect leads 1 & 2 (Anode) together.

NOTE: All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.	DATA SHEET #: RS0187C	DOC
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ssdi@ssdi-power.com \* www.ssdi-power.com

ELECTRICAL CHARACTERISTICS					
CHARACTERISTICS SYMBOL		MAXIMUM	UNIT		
Instantaneous Forward Voltage Drop <sup>1/</sup> (I <sub>F</sub> = 1 Adc, T <sub>A</sub> = 25°C, Pulse) (I <sub>F</sub> = 5 Adc, T <sub>A</sub> = 25°C, Pulse)	$ m V_{F1}$	0.56 0.73	Vdc		
Instantaneous Forward Voltage Drop (I <sub>F</sub> = 5 Adc, T <sub>A</sub> = -55°C, Pulse)	$ m V_{F2}$	0.8 Vdc			
Reverse Leakage Current (Rated V <sub>R</sub> , T <sub>A</sub> = 25°C, Pulse)	$I_{R1}$	100 μΑ			
Reverse Leakage Current (Rated V <sub>R</sub> , T <sub>A</sub> = 100°C, Pulse)	$I_{R2}$	5 mA			
Junction Capacitance (V <sub>R</sub> = 10 Vdc, T <sub>A</sub> = 25°C, f = 1 MHz)	C <sub>J</sub>	400	pF		

Notes:

2/ VF as measured between pins 1 and 2 in common, within .100" from the case, and pin 3 directly at the case.

